

Vishay Siliconix

Dual P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
- 30	0.080 at V _{GS} = - 10 V	- 3.9		
	0.135 at V _{GS} = - 4.5 V	- 3.0		

FEATURES

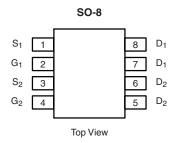
- Halogen-free According to IEC 61249-2-21
 Definition
- TrenchFET[®] Power MOSFETs

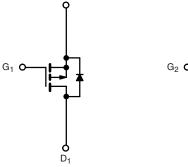
S₁

Compliant to RoHS Directive 2002/95/EC



Available







 S_2

Ordering Information: Si4947ADY-T1-E3 (Lead (Pb)-free) Si4947ADY-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	$T_A = 25$ °C, unles	ss otherwise r	noted			
Parameter		Symbol	10 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 30		V	
Gate-Source Voltage		V _{GS}	± 20			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	- 3.9	- 3.0		
	T _A = 70 °C		- 3.1	- 2.4		
Pulsed Drain Current		I _{DM}	- 20		A	
Continuous Source Current (Diode Conduction) ^a		۱ _S	- 1.7 - 1.0		I _S - 1.7 - 1.	
Maximum Power Dissipation ^a	T _A = 25 °C	P _D	2.0	1.2	w	
	T _A = 70 °C		1.3	0.76		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	R _{thJA}	54	62.5		
Maximum Junction-to-Ambient ^a	Steady State		87	105	°C/W	
Maximum Junction-to-Foot	Steady State		34	45		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static			•				
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1.0			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$\begin{tabular}{ c c c c c } \hline V_{DS} = -30 \ V, \ V_{GS} = 0 \ V \\ \hline V_{DS} = -30 \ V, \ V_{GS} = 0 \ V, \ T_J = 70 \ ^\circ C \end{tabular}$		- 1			
					- 10	μA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 15			Α	
Drain-Source On-State Resistance ^a	Р	$V_{GS} =$ - 10 V, I _D = - 3.9 A		0.062	0.080		
	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -3.0 \text{ A}$		0.105	0.135	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -15$ V, $I_{D} = -2.5$ A		5.0		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1.7 A, V _{GS} = 0 V		- 0.82	- 1.2	V	
Dynamic ^b			•	•			
Total Gate Charge	Qg			5.8	8		
Gate-Source Charge	Q _{gs}	V_{DS} = - 10 V, V_{GS} = - 5 V, I_{D} = - 3.9 A		2		nC	
Gate-Drain Charge	Q _{gd}			1.9		1	
Turn-On Delay Time	t _{d(on)}			8	15		
Rise Time	t _r	V_{DD} = - 10 V, R_L = 10 Ω		9	18	ns	
Turn-Off Delay Time	t _{d(off)}	$\text{I}_\text{D}\cong$ - 1 A, V_GEN = - 10 V, R_g = 6 Ω		21	40		
Fall Time	t _f			10	20		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.7 A, dl/dt = 100 A/μs		27	40		

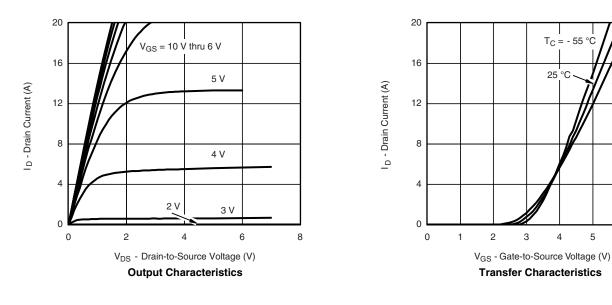
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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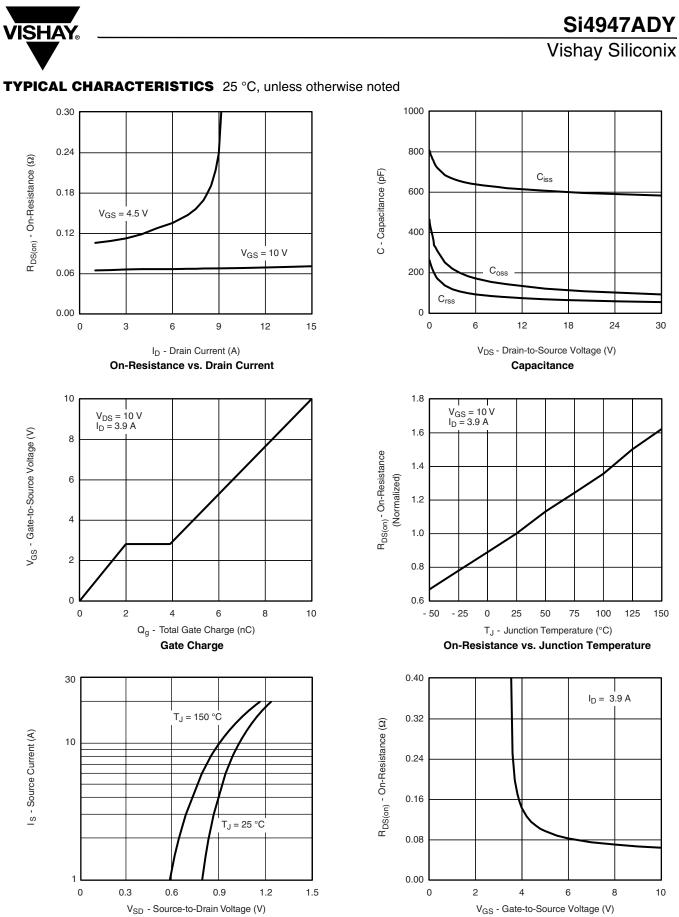
- 55

125 °C

6

7

°C

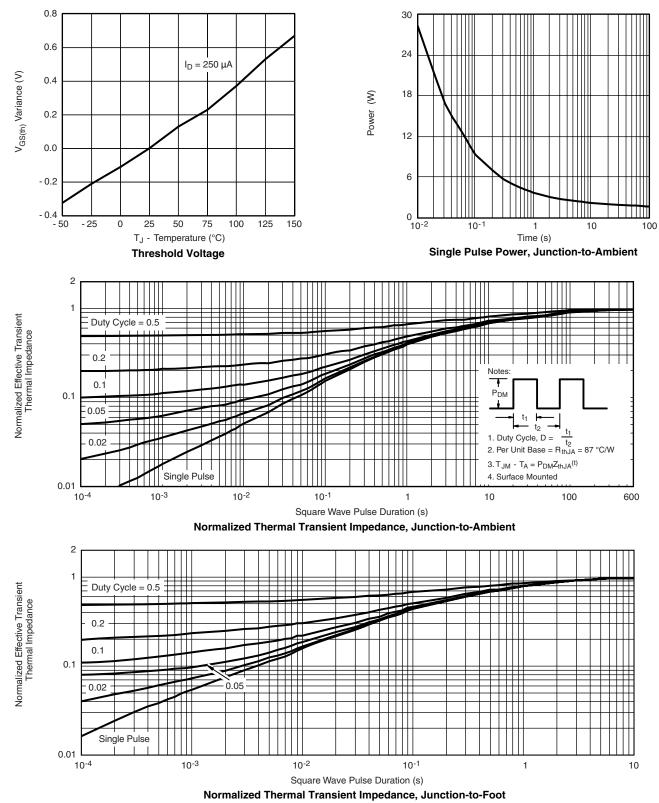


Source-Drain Diode Forward Voltage

Document Number: 71101 S09-0870-Rev. D, 18-May-09 On-Resistance vs. Gate-to-Source Voltage

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?71101.





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